# NSN 5961-01-061-9857

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#### **Inclosure Material:**

Metal

## **Overall Length:**

Between 0.250 inches and 0.340 inches

# **Overall Diameter:**

0.620 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

-120.0 breakdown voltage, collector-to-base, emitter open and -120.0 breakdown voltage, collector-to-emitter, base open and -6.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between -5.00 amperes source cutoff current and -20.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

40.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

#### Test Data Document:

88818-a532a034 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

2 pin and 1 case Shelf Life: N/a Unit Of Measure: --Demilitarization: No

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